

acid), polyacrylic acid, polyacrylamide, aminopolyacrylamide, ammonium polyacrylate, sodium polyacrylate, ammonium polyamidate, sodium polyamidate, polyglyoxylic acid, etc.; and vinyl polymers such as polyvinyl alcohol, polyvinylpyrrolidone, polyacrolein, etc.--

Please delete the paragraph at page 27, lines 14-20, and substitute therefor the following new paragraph:

--In a case where a protective film-forming agent is divided into three portions to be separately in three constituent elements, the metal-polishing liquid material may be composed of, for example, a first constituent element A that comprises an oxidizing agent and a part of the protective film-forming agent, a second constituent element B that comprises an oxidized-metal etchant and another part of the protective film-forming agent, and a third constituent element C that comprises the remaining part of the protective film-forming agent and a dissolution promoter.--

IN THE CLAIMS

Please amend the claims presently in the application as follows:

4. (Amended) The metal-polishing liquid material according to claim 2, wherein the dissolution promoter is a surfactant.

SUB 17
A1
6. (Amended) The metal-polishing liquid material according to claim 2, wherein the dissolution promoter is a solvent in which the solubility of the protective film-forming agent is at least 25 g/liter.

ad
10. (Amended) The metal-polishing liquid material according to claim 2, wherein at least a part of the protective film-forming agent is solid having a mean particle size of at most 100 μm .

11. (Amended) The metal-polishing liquid material according to claim 2, further comprising abrasive grains.

B
17. (Amended) A method for producing a metal-polishing liquid, comprising a step of diluting the metal-polishing liquid material of claim 2 with a diluent.

ad
20. (Amended) The method for producing a metal-polishing liquid according to claim 19, wherein the diluent is water or an aqueous diluent solution.

Please add the following new claims to the application:

all
--27. The metal-polishing liquid material according to claim 1, wherein the dissolution promoter is a surfactant.

28. The metal-polishing liquid material according to claim 27, wherein the surfactant is at least one of esters,

SUB 7
B1
ethers, polysaccharides, salts of amino acids, polycarboxylic acids, salts of polycarboxylic acids, vinyl polymers, sulfonic acids, sulfonates, and amides.

29. The metal-polishing liquid material according to claim 1, wherein the dissolution promoter is a solvent in which the solubility of the protective film-forming agent is at least 25 g/liter.

B
30. The metal-polishing liquid material according to claim 29, wherein the solvent is a good solvent for the protective film-forming agent.

31. The metal-polishing liquid material according to claim 29, wherein the solvent is at least one of alcohols, ethers and ketones.

32. The metal-polishing liquid material according to claim 29, wherein the amount of the solvent is smaller than 50 g relative to 100 g of a total amount of the material.

33. The metal-polishing liquid material according to claim 1, wherein at least a part of the protective film-forming agent is solid having a mean particle size of at most 100 μm .

34. The metal-polishing liquid material according to claim 1, further comprising abrasive grains.

35. A method for producing a metal-polishing liquid, comprising a step of diluting the metal-polishing liquid material of claim 1 with a diluent.

all could 36. The method for producing a metal-polishing liquid according to claim 17, wherein the diluent is water or an aqueous diluent solution.--

0969347, 090701